

74LV123

Dual retriggerable monostable multivibrator with reset

Rev. 7 — 12 December 2011

Product data sheet

1. General description

The 74LV123 is a low-voltage Si-gate CMOS device and is pin and function compatible with the 74HC123; 74HCT123. It is a dual retriggerable monostable multivibrator which uses three methods to control the output pulse width:

1. The basic pulse time is programmed by the selection of an external resistor (R_{EXT}) and capacitor (C_{EXT}). These are normally connected as shown in [Figure 9](#).
2. Once triggered, the basic output pulse width may be extended by retriggering the gated active LOW-going edge input ($n\overline{A}$) or the active HIGH-going edge input (nB). By repeating this process, the output pulse period ($nQ = \text{HIGH}$, $n\overline{Q} = \text{LOW}$) can be made as long as desired (see [Figure 12](#)).
3. Alternatively, an output delay can be terminated at any time by a LOW-going edge on input $n\overline{RD}$, which also inhibits the triggering (see [Figure 13](#)).

Schmitt-trigger action in the $n\overline{A}$ and nB inputs makes the circuit highly tolerant of slower input rise and fall times.

2. Features and benefits

- Optimized for low-voltage applications: 1.0 V to 5.5 V
- Accepts TTL input levels between $V_{CC} = 2.7 \text{ V}$ and $V_{CC} = 3.6 \text{ V}$
- Typical output ground bounce: $< 0.8 \text{ V}$ at $V_{CC} = 3.3 \text{ V}$ and $T_{amb} = 25 \text{ }^{\circ}\text{C}$
- Typical HIGH-level output voltage (V_{OH}) undershoot: $> 2 \text{ V}$ at $V_{CC} = 3.3 \text{ V}$ and $T_{amb} = 25 \text{ }^{\circ}\text{C}$
- DC triggered from active HIGH or active LOW inputs
- Retriggerable for very long pulses up to 100 % duty factor
- Direct reset terminates output pulses
- Schmitt-trigger action on all inputs except for the reset input

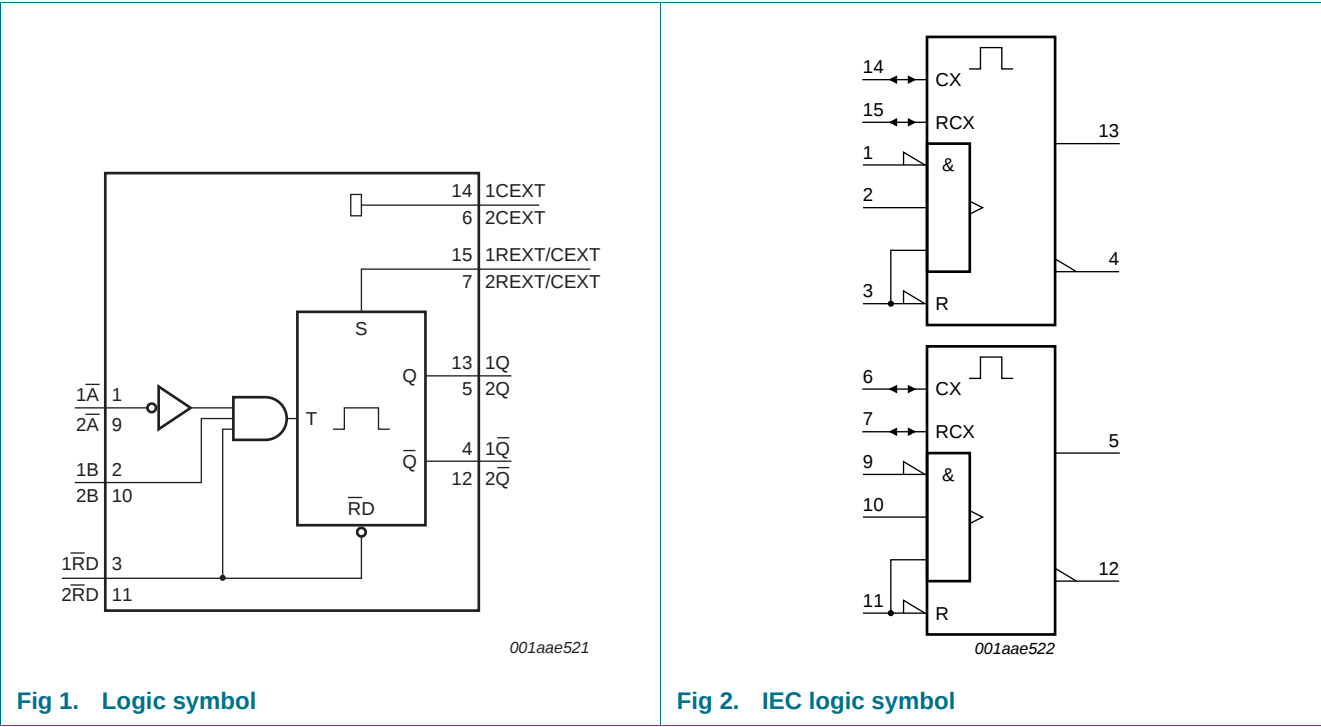


3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74LV123N	−40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4
74LV123D	−40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74LV123DB	−40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
74LV123PW	−40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74LV123BQ	−40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm	SOT763-1

4. Functional diagram



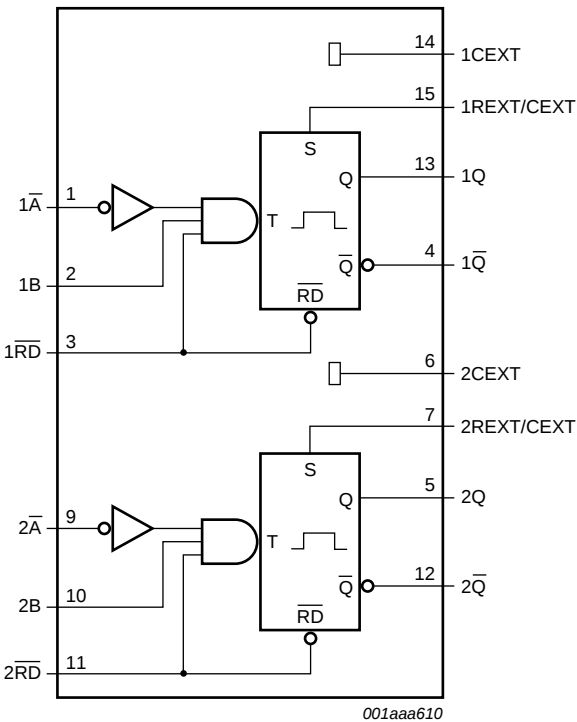
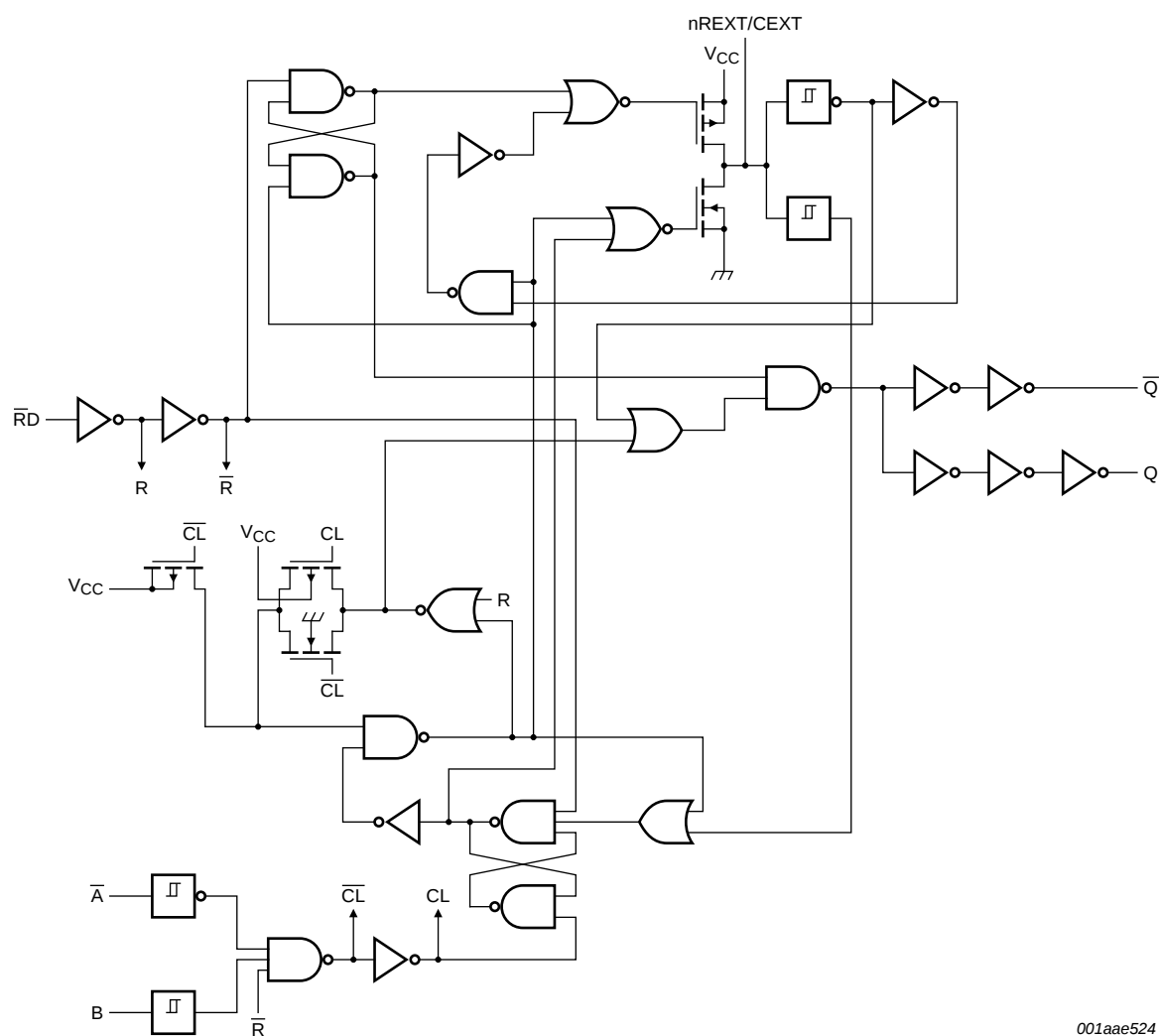


Fig 3. Functional diagram



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Fig 4. Logic diagram

5. Pinning information

5.1 Pinning

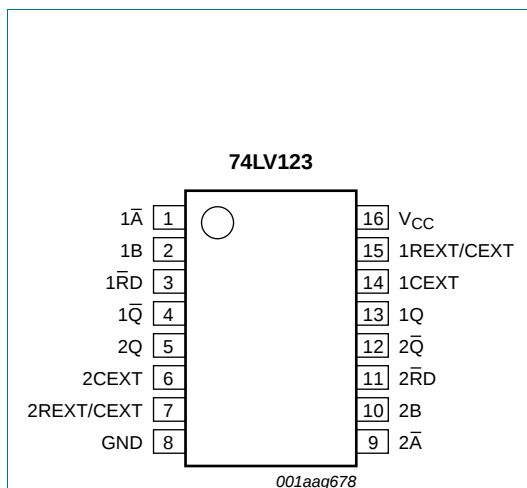
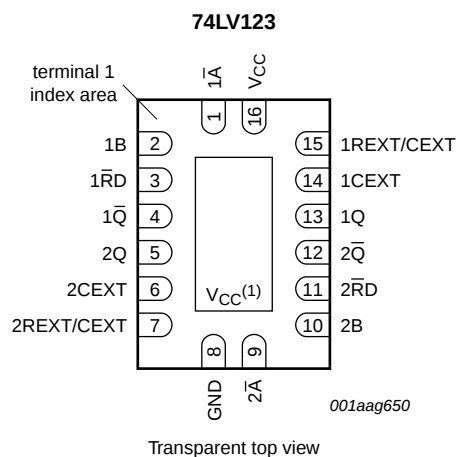


Fig 5. Pin configuration for DIP16, SO16, SSOP16 and TSSOP16



- (1) The die substrate is attached to this pad using conductive die attach material. It cannot be used as a supply pin or input.

Fig 6. Pin configuration for DHVQFN16

5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
$\overline{1A}$	1	negative-edge triggered input 1
1B	2	positive-edge triggered input 1
$\overline{1RD}$	3	direct reset LOW and positive-edge triggered input 1
$\overline{1Q}$	4	active LOW output 1
2Q	5	active HIGH output 2
2CEXT	6	external capacitor connection 2
2REXT/CEXT	7	external resistor and capacitor connection 2
GND	8	ground (0 V)
$\overline{2A}$	9	negative-edge triggered input 2
2B	10	positive-edge triggered input 2
$\overline{2RD}$	11	direct reset LOW and positive-edge triggered input 2
$\overline{2Q}$	12	active LOW output 2
1Q	13	active HIGH output 1
1CEXT	14	external capacitor connection 1
1REXT/CEXT	15	external resistor and capacitor connection 1
V_{CC}	16	supply voltage

6. Functional description

Table 3. Function table^[1]

Input			Output	
nRD	nA	nB	nQ	nQ
L	X	X	L	H
X	H	X	L ^[2]	H ^[2]
X	X	L	L ^[2]	H ^[2]
H	L	↑		
H	↓	H		
↑	L	H		

- [1] H = HIGH voltage level;
 L = LOW voltage level;
 X = don't care;
 ↑ = LOW-to-HIGH transition;
 ↓ = HIGH-to-LOW transition;

 = one HIGH level output pulse

 = one LOW level output pulse

- [2] If the monostable multivibrator was triggered before this condition was established, the pulse will continue as programmed.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7	V
I_{IK}	input clamping current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$	[1] -	± 20	mA
I_{OK}	output clamping current	$V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$	[1] -	± 50	mA
I_O	output current	except for pins nREXT/CEXT; $V_O = -0.5\text{ V}$ to $(V_{CC} + 0.5\text{ V})$	[1] -	± 25	mA
I_{CC}	supply current		-	+50	mA
I_{GND}	ground current		-	-50	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40\text{ °C}$ to $+125\text{ °C}$			
		DIP16 package	[2] -	750	mW
		SO16 package	[3] -	500	mW
		SSOP16 package	[4] -	500	mW
		TSSOP16 package	[4] -	500	mW
		DHVQFN16 package	[5] -	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

[3] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

[4] For SSOP16 and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

[5] For DHVQFN16 package: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		[1] 1.0	3.3	5.5	V
V_I	input voltage		0	-	V_{CC}	V
V_O	output voltage		0	-	V_{CC}	V
T_{amb}	ambient temperature	in free air	-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.0\text{ V}$ to 2.0 V	[2] -	-	500	ns/V
		$V_{CC} = 2.0\text{ V}$ to 2.7 V	-	-	200	ns/V
		$V_{CC} = 2.7\text{ V}$ to 3.6 V	-	-	100	ns/V
		$V_{CC} = 3.6\text{ V}$ to 5.5 V	-	-	50	ns/V

[1] The 74LV123 is guaranteed to function down to $V_{CC} = 1.0\text{ V}$ (input levels GND or V_{CC}); [Section 9 "Static characteristics"](#) are guaranteed from $V_{CC} = 1.2\text{ V}$ to $V_{CC} = 5.5\text{ V}$.

[2] Except for Schmitt-trigger inputs $\overline{nA}$ and nB .

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
T_{amb} = –40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 1.2 V	0.9	-	-	V
		V _{CC} = 2.0 V	1.4	-	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 1.2 V	-	-	0.3	V
		V _{CC} = 2.0 V	-	-	0.6	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3 × V _{CC}	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = –100 µA; V _{CC} = 1.2 V	-	1.2	-	V
		I _O = –100 µA; V _{CC} = 2.0 V	1.8	2.0	-	V
		I _O = –100 µA; V _{CC} = 2.7 V	2.5	2.7	-	V
		I _O = –100 µA; V _{CC} = 3.0 V	2.8	3.0	-	V
		I _O = –100 µA; V _{CC} = 4.5 V	4.3	4.5	-	V
		I _O = –6 mA; V _{CC} = 3.0 V	2.40	2.82	-	V
		I _O = –12 mA; V _{CC} = 4.5 V	3.60	4.20	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 100 µA; V _{CC} = 1.2 V	-	0	-	V
		I _O = 100 µA; V _{CC} = 2.0 V	-	0	0.2	V
		I _O = 100 µA; V _{CC} = 2.7 V	-	0	0.2	V
		I _O = 100 µA; V _{CC} = 3.0 V	-	0	0.2	V
		I _O = 100 µA; V _{CC} = 4.5 V	-	0	0.2	V
		I _O = 6 mA; V _{CC} = 3.0 V	-	0.25	0.40	V
		I _O = 12 mA; V _{CC} = 4.5 V	-	0.35	0.55	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V	-	-	1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V	-	-	20.0	µA
ΔI _{CC}	additional supply current	V _I = V _{CC} – 0.6 V; V _{CC} = 2.7 V to 3.6 V	-	-	500	µA
C _I	input capacitance		-	3.5	-	pF
T_{amb} = –40 °C to +125 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 1.2 V	0.9	-	-	V
		V _{CC} = 2.0 V	1.4	-	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 1.2 V	-	-	0.3	V
		V _{CC} = 2.0 V	-	-	0.6	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3 × V _{CC}	V

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = -100 µA; V _{CC} = 1.2 V	-	-	-	V
		I _O = -100 µA; V _{CC} = 2.0 V	1.8	-	-	V
		I _O = -100 µA; V _{CC} = 2.7 V	2.5	-	-	V
		I _O = -100 µA; V _{CC} = 3.0 V	2.8	-	-	V
		I _O = -100 µA; V _{CC} = 4.5 V	4.3	-	-	V
		I _O = -6 mA; V _{CC} = 3.0 V	2.2	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 100 µA; V _{CC} = 1.2 V	-	-	-	V
		I _O = 100 µA; V _{CC} = 2.0 V	-	-	0.2	V
		I _O = 100 µA; V _{CC} = 2.7 V	-	-	0.2	V
		I _O = 100 µA; V _{CC} = 3.0 V	-	-	0.2	V
		I _O = 100 µA; V _{CC} = 4.5 V	-	-	0.2	V
		I _O = 6 mA; V _{CC} = 3.0 V	-	-	0.5	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V	-	-	1.0	µA
		V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V	-	-	160	µA
ΔI _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; V _{CC} = 2.7 V to 3.6 V	-	-	850	µA

[1] All typical values are measured at T_{amb} = 25 °C.

10. Dynamic characteristics

Table 7. Dynamic characteristics

$GND = 0\text{ V}$; $t_r = t_f \leq 2.5\text{ ns}$; for test circuit see [Figure 8](#).

Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
Propagation delay; see Figure 7								
t _{pd}	propagation delay	nRD, nA and nB to nQ ^[2]						
		V _{CC} = 1.2 V	-	120	-	-	-	ns
		V _{CC} = 2.0 V	-	40	76	-	92	ns
		V _{CC} = 2.7 V	-	30	56	-	68	ns
		V _{CC} = 3.0 V to 3.6 V	-	25	48	-	57	ns
		V _{CC} = 4.5 V to 5.5 V	-	18	40	-	46	ns
		nRD to nQ (reset) ^[2]						
		V _{CC} = 1.2 V	-	100	-	-	-	ns
		V _{CC} = 2.0 V	-	30	57	-	68	ns
		V _{CC} = 2.7 V	-	23	43	-	51	ns
		V _{CC} = 3.0 V to 3.6 V	-	20	38	-	45	ns
		V _{CC} = 4.5 V to 5.5 V	-	14	31	-	36	ns
Inputs nA, nB and nRD; see Figure 7								
t _w	pulse width	nA = LOW						
		V _{CC} = 2.0 V	30	5	-	40	-	ns
		V _{CC} = 2.7 V	25	3.5	-	30	-	ns
		V _{CC} = 3.0 V to 3.6 V	20	3.0	-	25	-	ns
		V _{CC} = 4.5 V to 5.5 V	15	2.5	-	20	-	ns
		nB = HIGH						
		V _{CC} = 2.0 V	30	13	-	40	-	ns
		V _{CC} = 2.7 V	25	8	-	30	-	ns
		V _{CC} = 3.0 V to 3.6 V	20	7	-	25	-	ns
		V _{CC} = 4.5 V to 5.5 V	15	5	-	20	-	ns
		nRD = LOW; see Figure 13						
		V _{CC} = 2.0 V	35	6	-	45	-	ns
		V _{CC} = 2.7 V	30	5	-	40	-	ns
		V _{CC} = 3.0 V to 3.6 V	25	4	-	30	-	ns
		V _{CC} = 4.5 V to 5.5 V	20	3	-	25	-	ns
t _{rtrig}	retrigger time	nB to nA; see Figure 12						
		V _{CC} = 2.0 V	-	70	-	-	-	ns
		V _{CC} = 2.7 V	-	55	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	45	-	-	-	ns
		V _{CC} = 4.5 V to 5.5 V	-	40	-	-	-	ns

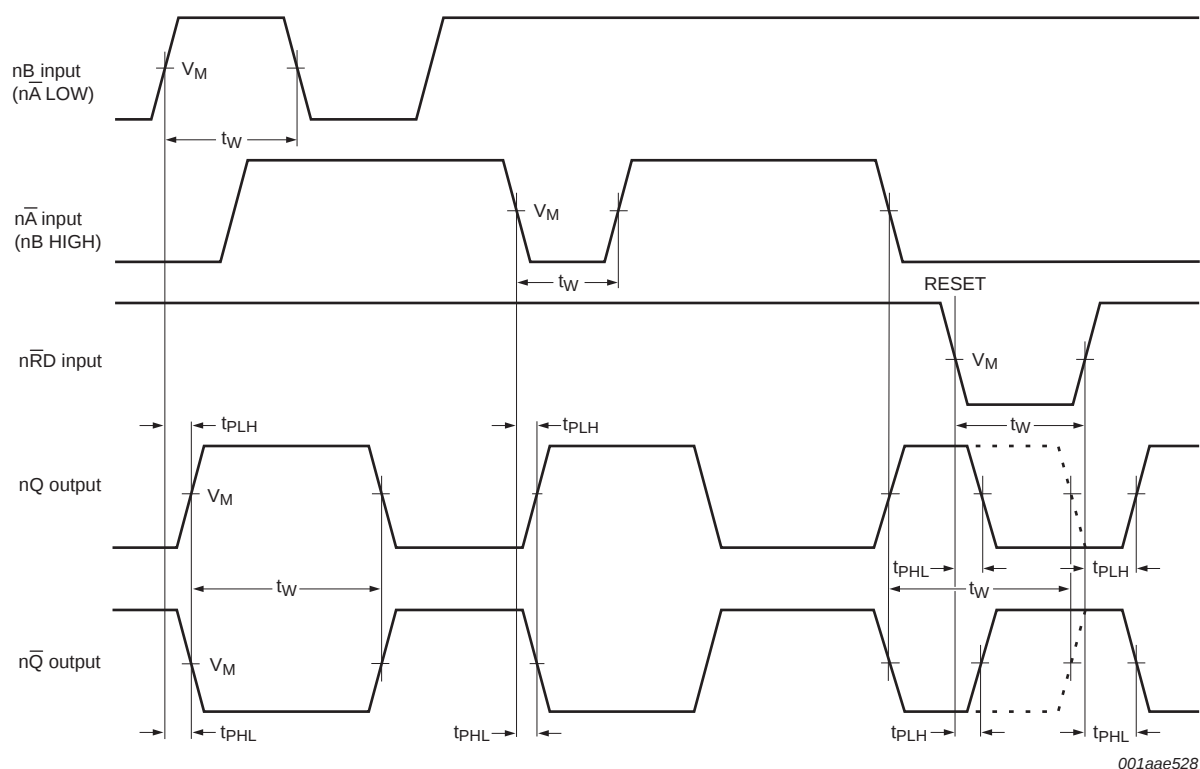
Table 7. Dynamic characteristics ...continued

GND = 0 V; $t_r = t_f \leq 2.5$ ns; for test circuit see [Figure 8](#).

Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
Outputs; nQ̄ = LOW and nQ = HIGH, see Figure 7								
t _w	pulse width	C _{EXT} = 100 nF; R _{EXT} = 10 kΩ						
		V _{CC} = 2.0 V	-	470	-	-	-	ns
		V _{CC} = 2.7 V	-	460	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	450	-	-	-	ns
		V _{CC} = 4.5 V to 5.5 V	-	430	-	-	-	ns
		C _{EXT} = 0 pF; R _{EXT} = 5 kΩ						
		V _{CC} = 2.0 V	-	100	-	-	-	ns
		V _{CC} = 2.7 V	-	90	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	80	-	-	-	ns
		V _{CC} = 4.5 V to 5.5 V	-	70	-	-	-	ns
External components								
R _{EXT}	external resistance	see Figure 11						
		V _{CC} = 1.2 V	10	-	1000	-	-	kΩ
		V _{CC} = 2.0 V	5	-	1000	-	-	kΩ
		V _{CC} = 2.7 V	3	-	1000	-	-	kΩ
		V _{CC} = 3.0 V to 3.6 V	2	-	1000	-	-	kΩ
		V _{CC} = 4.5 V to 5.5 V	2	-	1000	-	-	kΩ
C _{EXT}	external capacitance	see Figure 11						
		V _{CC} = 1.2 V	-	-	-	-	-	pF
		V _{CC} = 2.0 V	-	-	-	-	-	pF
		V _{CC} = 2.7 V	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	-	-	-	-	pF
		V _{CC} = 4.5 V to 5.5 V	-	-	-	-	-	pF
Dynamic power dissipation								
C _{PD}	power dissipation capacitance	V _{CC} = 3.3 V; V _I = GND to V _{CC}						
			[5]	60	-	-	-	pF

[1] All typical values are measured at $T_{amb} = 25$ °C and nominal supply values ($V_{CC} = 3.3$ V and 5.0 V).[2] t_{pd} is the same as t_{PLH} and t_{PHL} ; $C_{EXT} = 0$ pF; $R_{EXT} = 5$ k Ω .[3] For other R_{EXT} and C_{EXT} combinations see [Figure 11](#) and [Section 12.1.1 "Basic timing"](#).[4] C_{EXT} has no limits.[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz; f_o = output frequency in MHz; C_L = output load capacitance in pF; V_{CC} = supply voltage in V; N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

11. Waveforms

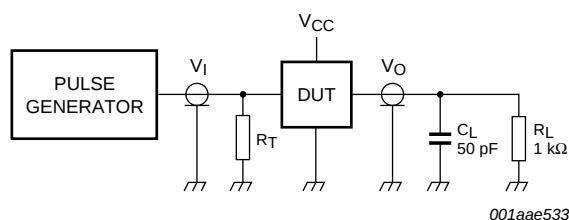


Measurement points are given in [Table 8](#).

Fig 7. Propagation delays from inputs ($\bar{nA}$, nB , $\bar{nRD}$) to outputs (nQ , $\bar{nQ}$)

Table 8. Measurement points

V_{CC}	V_M
$\geq 2.7\text{ V}$	1.5 V
$< 2.7\text{ V}$	$0.5 \times V_{CC}$



Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to Z_0 of the pulse generator.

Fig 8. Load circuitry for switching times

Table 9. Test data

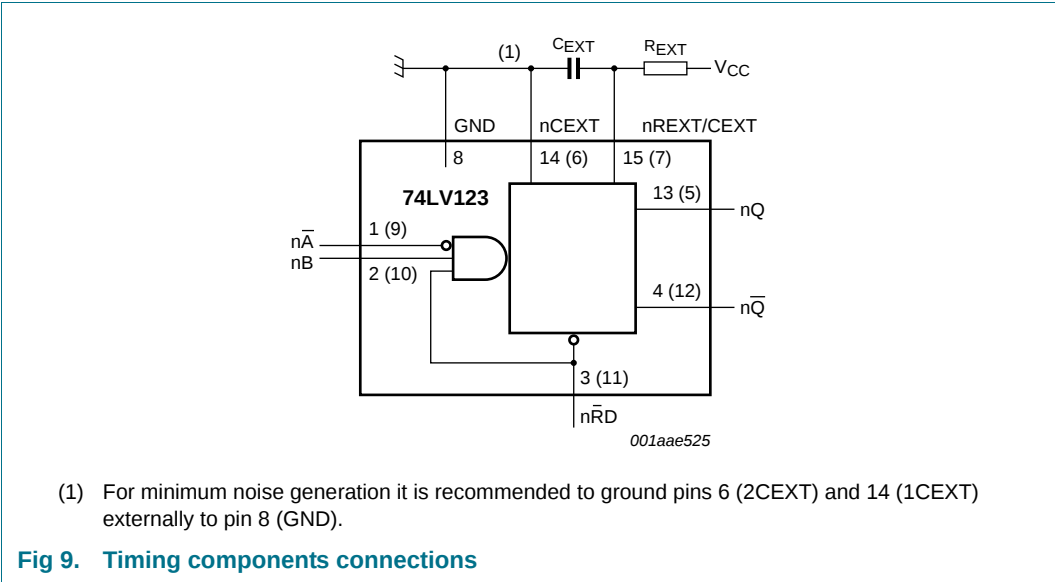
Supply voltage	Input		Load		Test
V _{CC}	V _I	t _r , t _f	C _L	R _L	
< 2.7 V	V _{CC}	≤ 2.5 ns	50 pF	1 kΩ	t _{PHL} , t _{PLH}
2.7 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	1 kΩ	t _{PHL} , t _{PLH}
≥ 4.5 V	V _{CC}	≤ 2.5 ns	50 pF	1 kΩ	t _{PHL} , t _{PLH}

12. Application information

12.1 Timing components

12.1.1 Basic timing

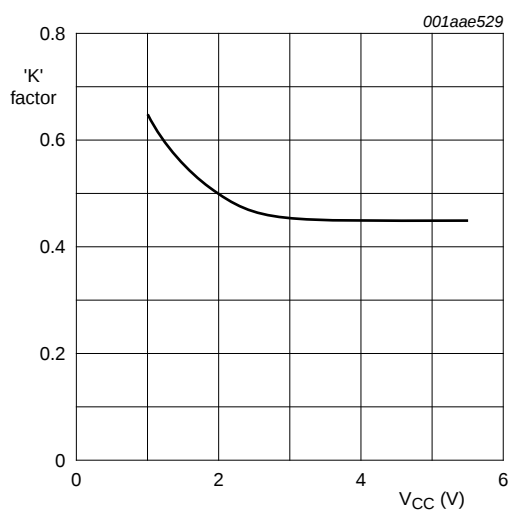
The basic output pulse width is essentially determined by the values of the external timing components R_{EXT} and C_{EXT}.



If C_{EXT} > 10 nF, the following formula is valid: t_W = K × R_{EXT} × C_{EXT} (typ.) where:

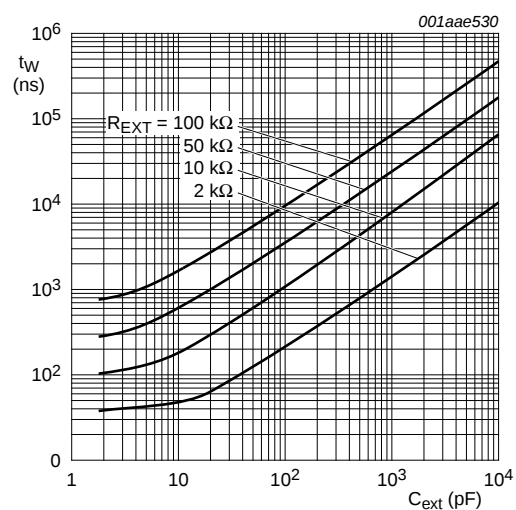
- t_W = output pulse width in ns
- R_{EXT} = external resistor in kΩ
- C_{EXT} = external capacitor in pF
- K = constant: this is 0.45 for V_{CC} = 5.0 V and 0.48 for V_{CC} = 2.0 V (see [Figure 10](#))

The inherent test jig and pin capacitance at pin 15 and pin 7 (nREXT/CEXT) is approximately 7 pF.



$C_{EXT} = 10 \text{ nF}$; $R_{EXT} = 10 \text{ k}\Omega$ to $100 \text{ k}\Omega$

Fig 10. Typical 'K' factor as a function of V_{CC}



$V_{CC} = 3.3 \text{ V}$ and $T_{amb} = 25 \text{ }^{\circ}\text{C}$

Fig 11. Typical output pulse width as a function of the external capacitance values

12.1.2 Retrigger timing

The time to retrigger the monostable multivibrator depends on the values of R_{EXT} and C_{EXT} . The output pulse width will only be extended when the time between the active going edges of the trigger pulses meets the minimum retrigger time. If $C_{EXT} > 10 \text{ pF}$, the next formula for the set-up time of a retrigger pulse is valid:

at $V_{CC} = 5.0 \text{ V}$: $t_{rtrig} = 30 + 0.19R_{EXT} \times C_{EXT}^{0.9} + 13 \times R_{EXT}^{1.05}$ (typ.)

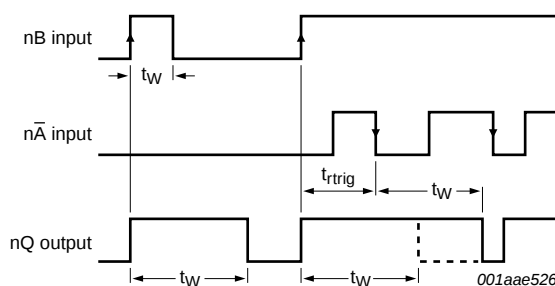
at $V_{CC} = 3.0 \text{ V}$: $t_{rtrig} = 41 + 0.15R_{EXT} \times C_{EXT}^{0.9} \times 1 \times R_{EXT}$ (typ.)

where:

t_{rtrig} = retrigger time in ns

C_{EXT} = external capacitor in pF

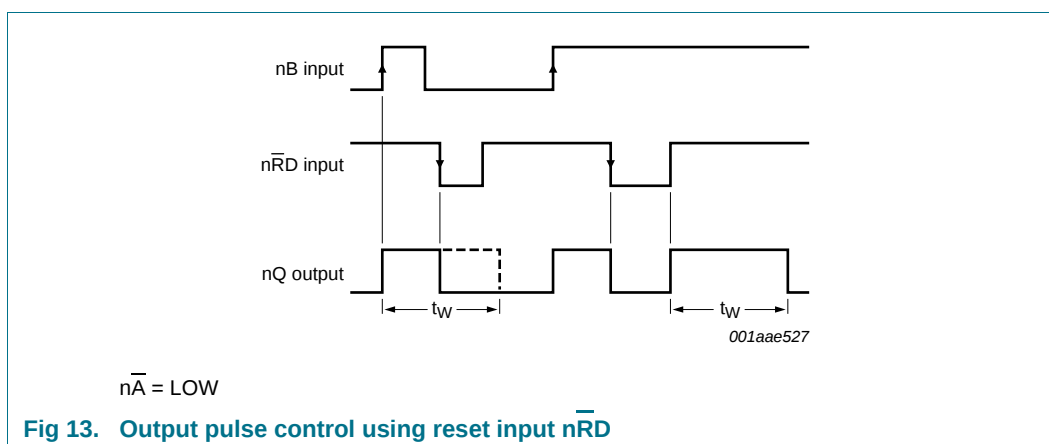
R_{EXT} = external resistor in $\text{k}\Omega$



$\overline{nRD} = \text{HIGH}$

Fig 12. Output pulse control using retrigger pulse $\overline{nA}$

12.1.3 Reset timing



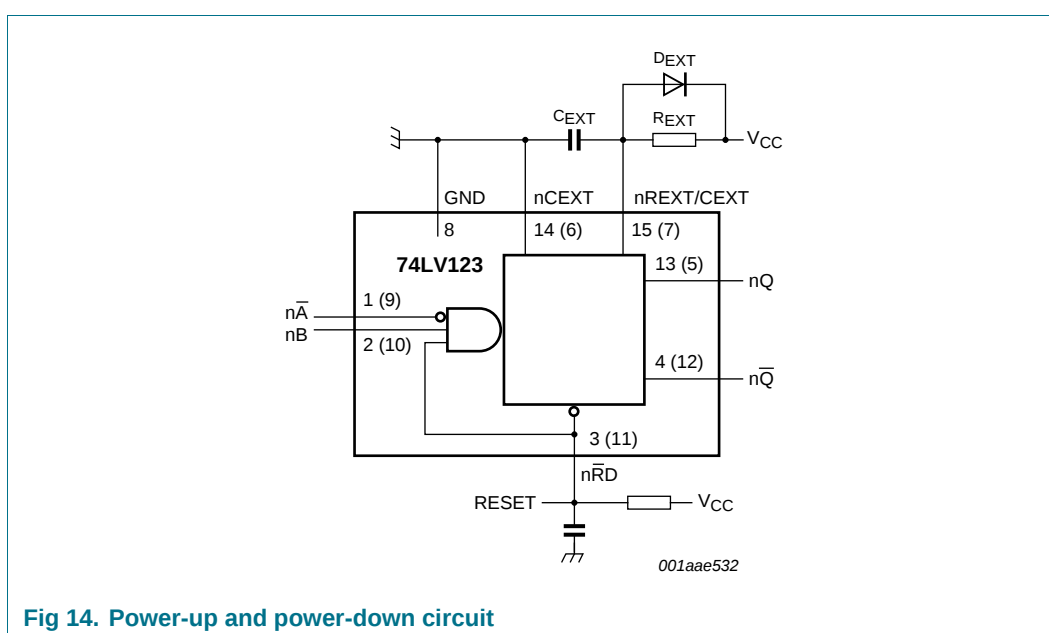
12.2 Power considerations

12.2.1 Power-up

When the monostable multivibrator is powered-up, it may produce an output pulse with a pulse width defined by the values of R_{EXT} and C_{EXT} . This output pulse can be eliminated using the RC circuit on pin $\bar{nRD}$ shown in [Figure 14](#).

12.2.2 Power-down

A large capacitor (C_{EXT}) may cause problems when powering-down the monostable due to the energy stored in this capacitor. When a system containing this device is powered-down or a rapid decrease of V_{CC} to zero occurs, the monostable may sustain damage, due to the capacitor discharging through the input protection diodes. To avoid this possibility, connect a damping diode D_{EXT} (preferably a germanium or Schottky type diode) able to withstand large current surges - see [Figure 14](#).



13. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4

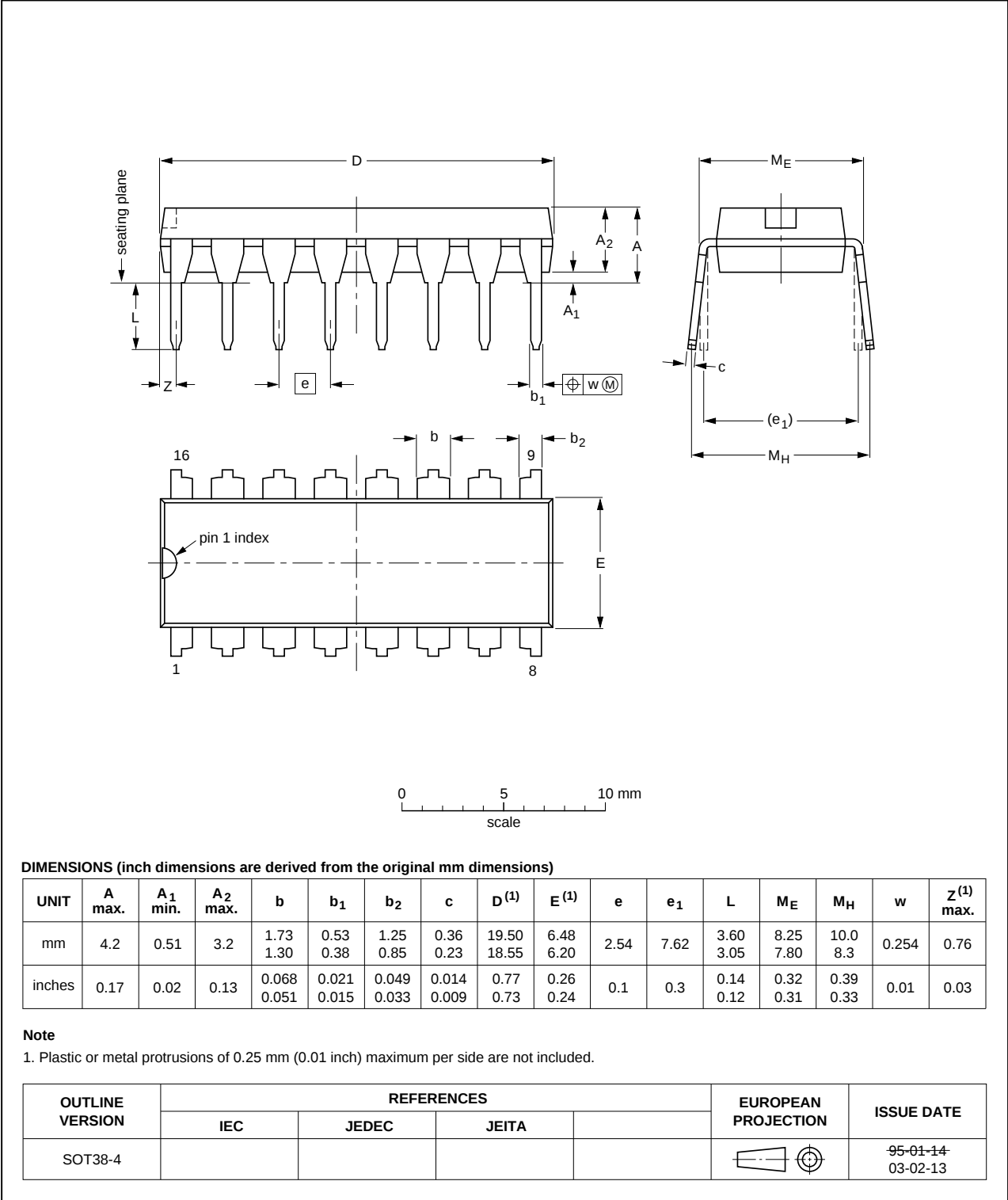
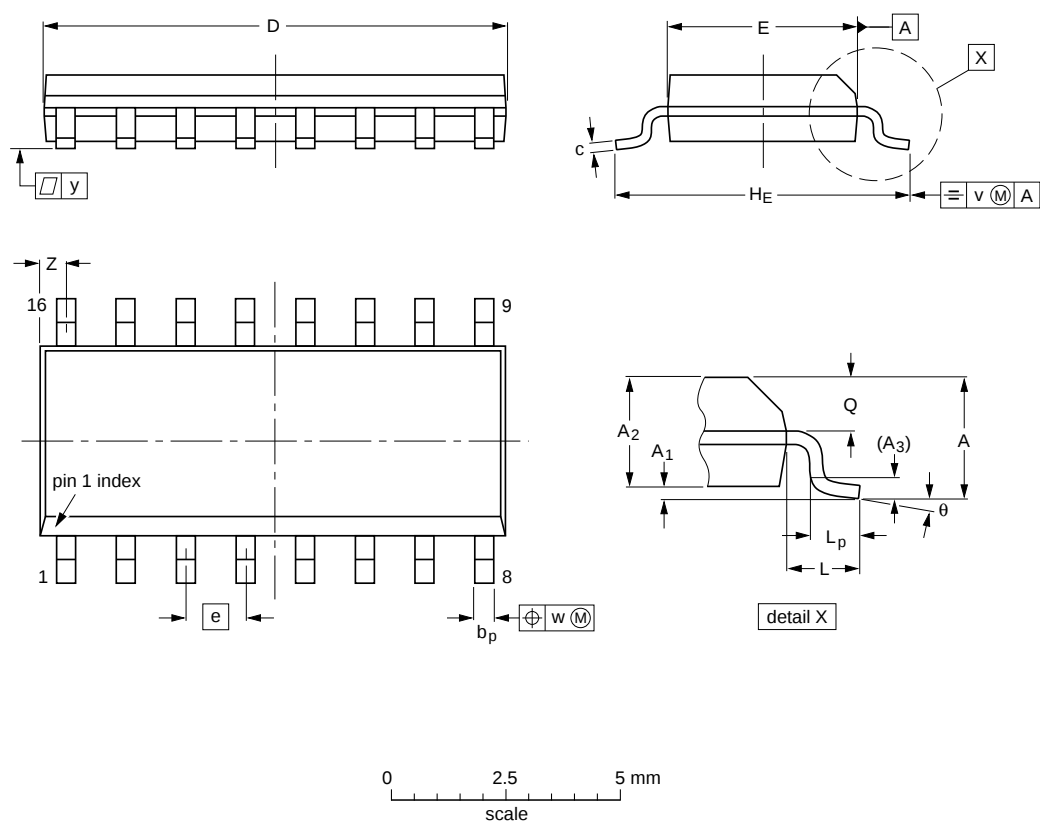


Fig 15. Package outline SOT38-4 (DIP16)

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	

Note
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT109-1	076E07	MS-012				99-12-27 03-02-19

Fig 16. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1

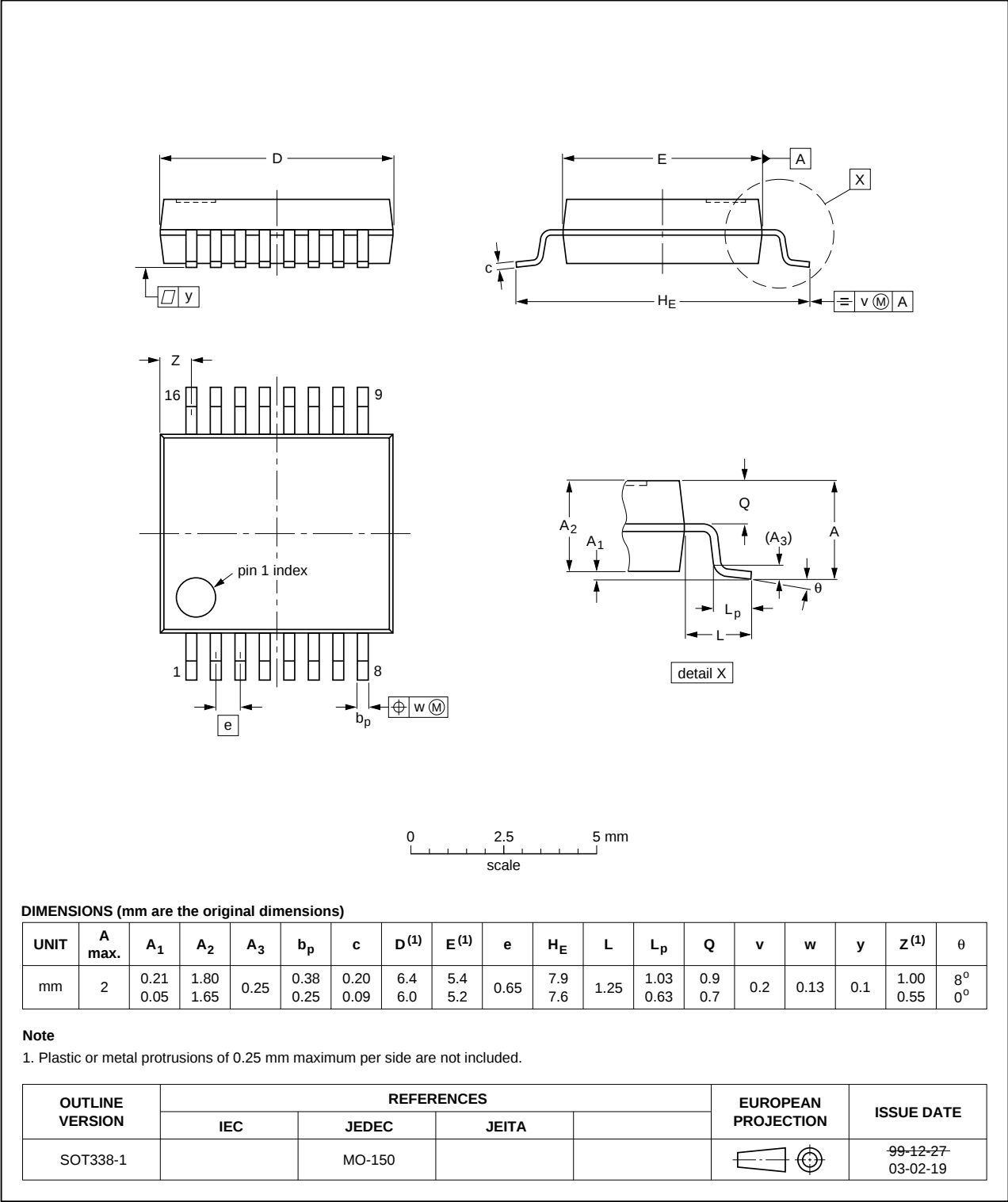


Fig 17. Package outline SOT338-1 (SSOP16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

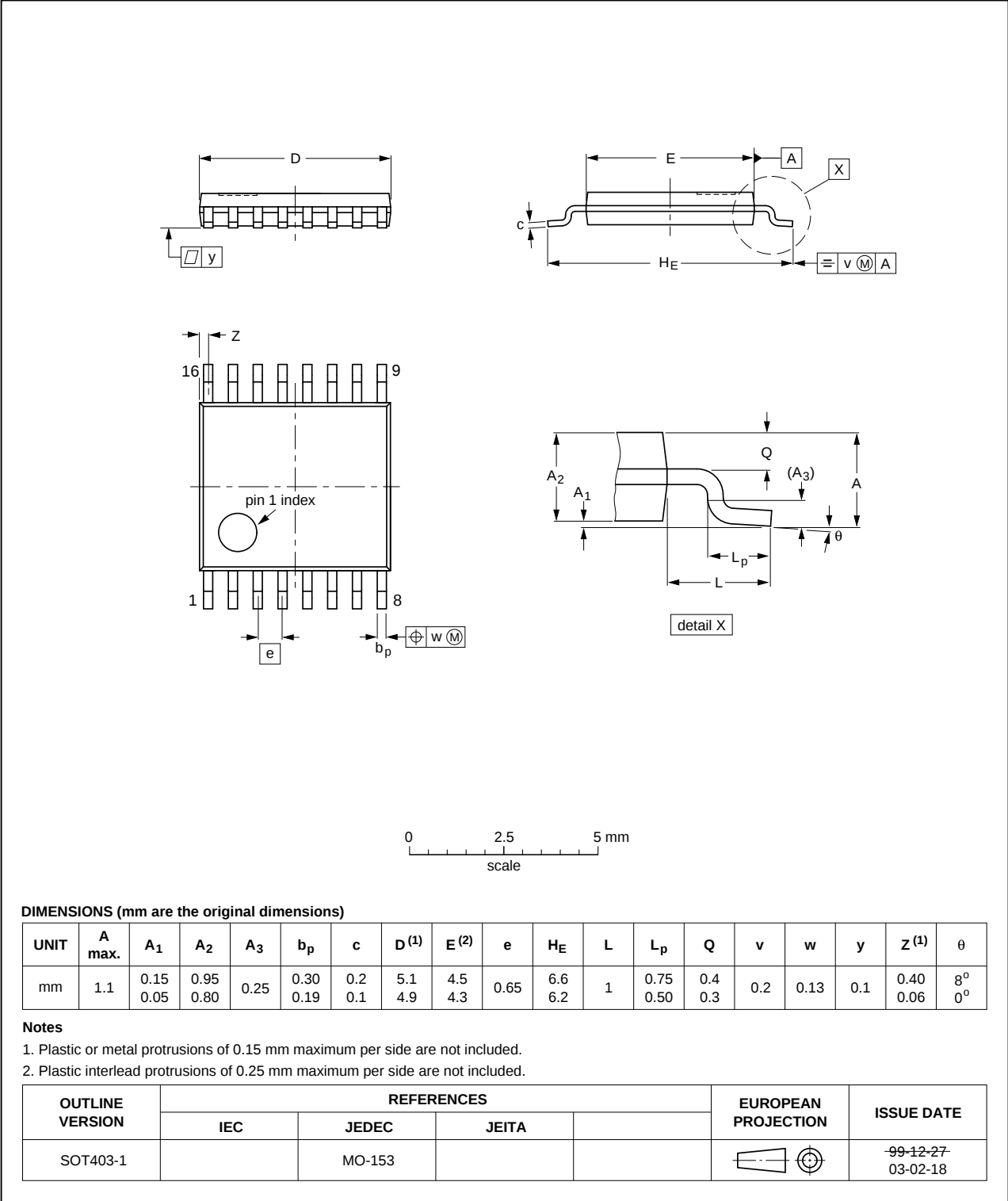


Fig 18. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm

SOT763-1

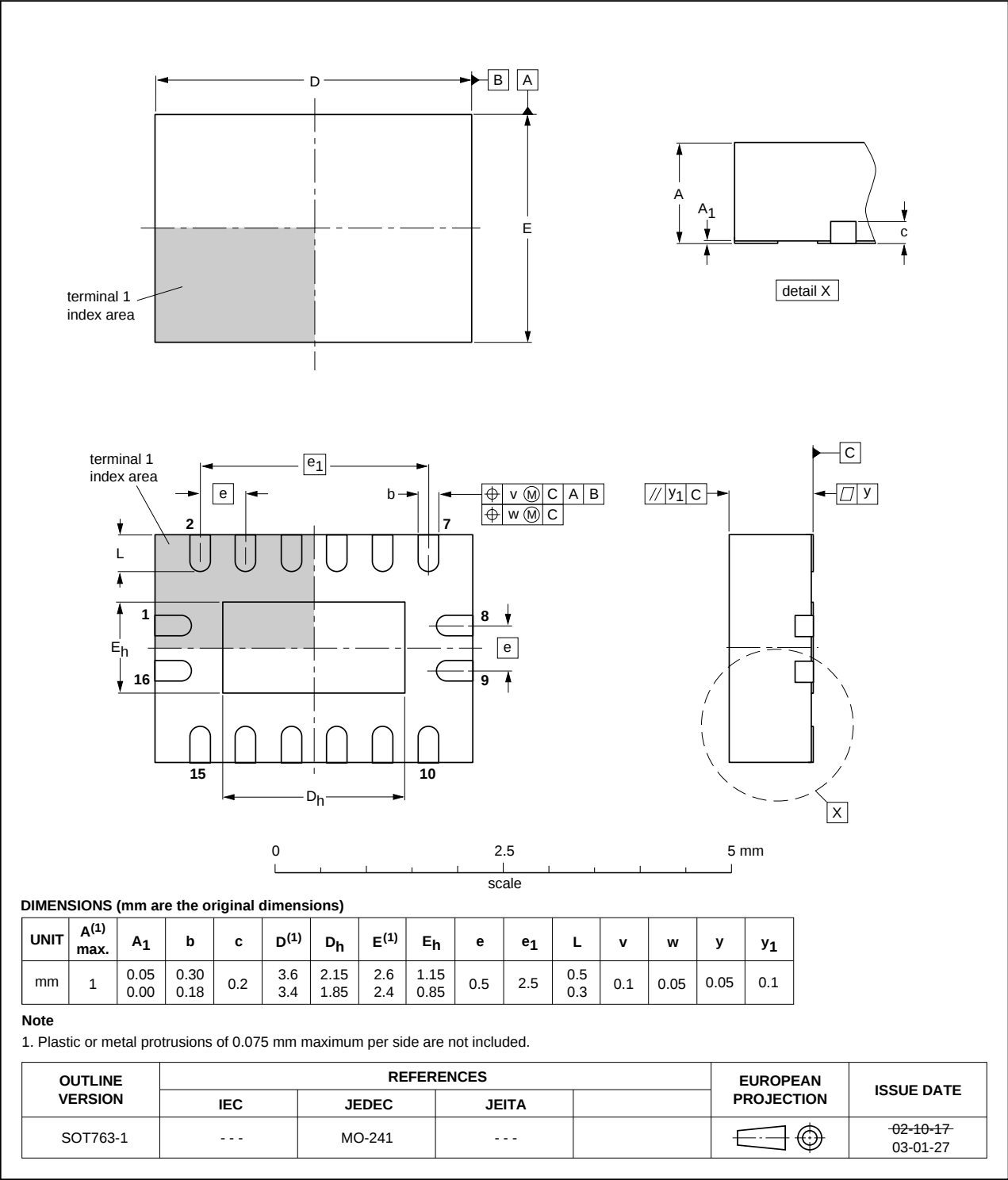


Fig 19. Package outline SOT736-1 (DHVQFN16)

14. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LV123 v.7	20111212	Product data sheet	-	74LV123 v.6
Modifications:	• Legal pages updated.			
74LV123 v.6	20110826	Product data sheet	-	74LV123 v.5
74LV123 v.5	20071108	Product data sheet	-	74LV123 v.4
74LV123 v.4	20070919	Product specification	-	74LV123 v.3
74LV123 v.3	20030313	Product specification	-	74LV123 v.2
74LV123 v.2	19980420	Product specification	-	74LV123 v.1
74LV123 v.1	19970204	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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